



40V P-Channel Enhancement Mode MOSFET

Voltage

-40 V

Current

-44 A

Features

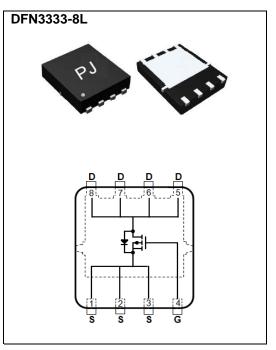
- R_{DS(ON)}, V_{GS}@-10V, I_D@-10A<17mΩ
- R_{DS(ON)}, V_{GS}@-4.5V, I_D@-8A<25mΩ
- Advanced Trench Process Technology
- High density cell design for ultralow on-resistance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: DFN3333-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.001 ounces, 0.03 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	-40	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20		
Continuous Drain Current(Note 4)	Tc=25°C	I _D	-44		
	Tc=100°C		-28	Α	
Pulsed Drain Current(Note 1)	Tc=25°C	I _{DM}	-135		
Power Dissipation	Tc=25°C	Po	59.5	14/	
	Tc=100°C		24	W	
Continuous Drain Current(Note 4)	T _A =25°C	l _D	-8.5		
	T _A =70°C		-7	Α	
Power Dissipation	T _A =25°C	Po	2	147	
	T _A =70°C		1.3	W	
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150	°C	
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	R ₀ JC	2.1	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static			1	•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-40	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.6	-2.5		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-10A	-	14	17	0	
		V _{GS} =-4.5V, I _D =-8A	-	20	25	mΩ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-40V, V _{GS} =0V	-	-	-1	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA	
Dynamic ^(Note 6)							
Total Gate Charge	Q_g	V _{DS} =-32V, I _D =-10A, V _{GS} =-4.5V ^(Note 1,2)	-	19	-	nC	
Gate-Source Charge	Q_{gs}		-	5.3	-		
Gate-Drain Charge	Q_{gd}		-	6.6	-		
Input Capacitance	Ciss	V _{DS} =-25V, V _{GS} =0V, f=1MHZ	-	2030	-	pF	
Output Capacitance	Coss		-	190	-		
Reverse Transfer Capacitance	Crss		-	139	-		
Turn-On Delay Time	td _(on)	\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	-	8.6	-		
Turn-On Rise Time	t r	V _{DS} =-20V, I _D =-1A, V _{GS} =-10V, R _G =6Ω (Note 1,2)	-	9.6	-	ns	
Turn-Off Delay Time	td _(off)		-	77	-		
Turn-Off Fall Time	t _f	(1000 1,2)	-	39	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	1		-	-	-44	А	
Diode Forward Current	Is						
Diode Forward Voltage	V _{SD}	Is=-1A, V _{GS} =0V	-	-0.7	-1	V	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

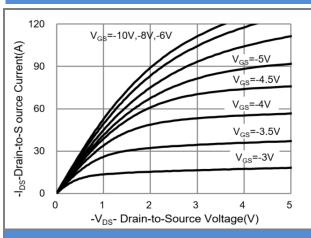


Fig.1 On-Region Characteristics

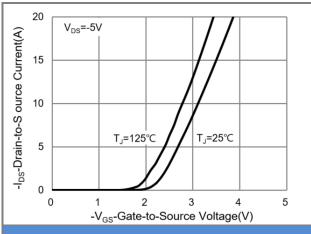


Fig.2 Transfer Characteristics

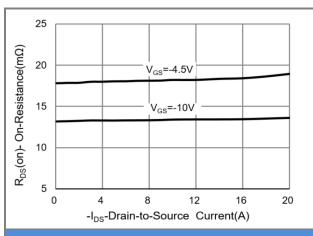


Fig.3 On-Resistance vs. Drain Current

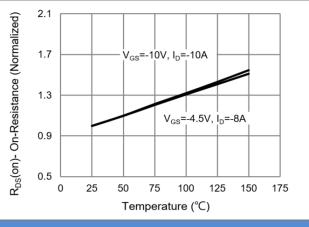


Fig.4 On-Resistance vs. Junction temperature

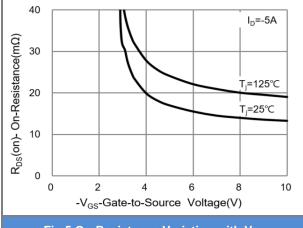


Fig.5 On-Resistance Variation with V_{GS}

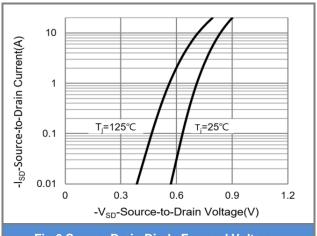


Fig.6 Source-Drain Diode Forward Voltage





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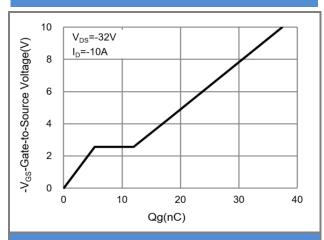


Fig.7 Gate-Charge Characteristics

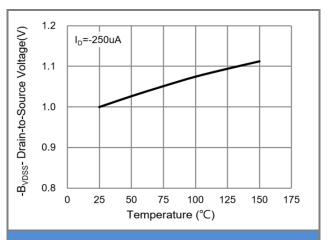


Fig.8 Breakdown Voltage Variation vs. Temperature

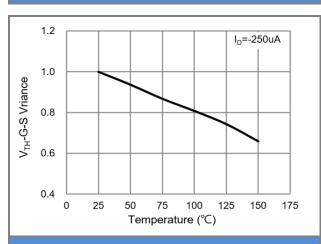


Fig.9 Threshold Voltage Variation with Temperature

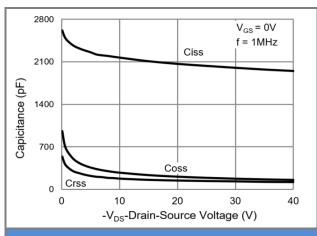
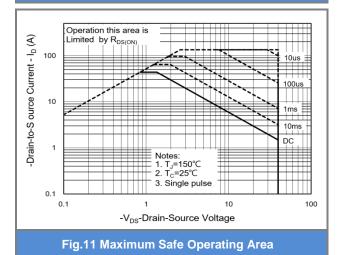


Fig.10 Capacitance vs. Drain-Source Voltage



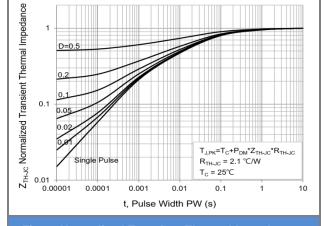


Fig.12 Normalized Transient Thermal Impedance

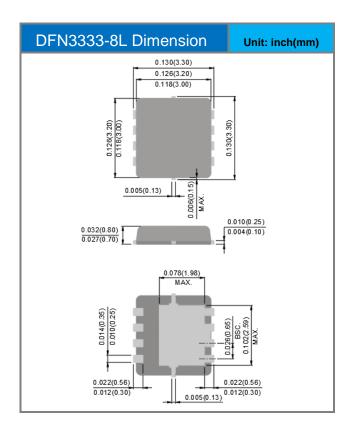


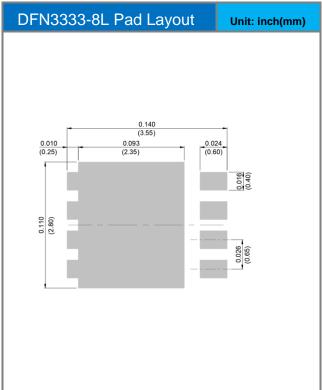


Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4441P-AU_R2_000A1	DFN3333-8L	5K pcs / 13" reel	4441	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout









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